

# **NCE N-Channel Super Trench II Power MOSFET**

## **Description**

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

# **Application**

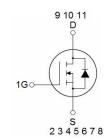
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

#### **General Features**

- $V_{DS}$  =60V, $I_D$  =340A  $R_{DS(ON)}$ =1.0m $\Omega$  , typical @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!





**Schematic Diagram** 

# **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP015N60LL	NCEP015N60LL	TOLL	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (T <sub>C</sub> =25℃)	I <sub>D</sub> (T <sub>C</sub> =25℃)	340	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> ((T <sub>C</sub> =100°C)	240	А
Pulsed Drain Current (Note 1)	I <sub>DM</sub>	1360	Α
Maximum Power Dissipation(Tc=25°C)	P <sub>D</sub> (T <sub>C</sub> =25℃)	350	W
Derating factor		2.3	W/℃
Single pulse avalanche energy (Note 5)	Eas	2880	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance.Junction-to-Case	Reic	0.43	°C/W
Thomas Redictance; surfaction to Case	IN⊕JC	0.10	~, ~,



# Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics					•	•
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)					•	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =170A	-	1.0	1.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =170A		150	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	9433	-	PF
Output Capacitance	Coss	$V_{DS}$ =30V, $V_{GS}$ =0V, F=1.0MHz	-	1647	-	PF
Reverse Transfer Capacitance	Crss	F=1.UIVIHZ	-	92.6	-	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t <sub>d(on)</sub>		-	20	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =30V, $I_{D}$ =170A $V_{GS}$ =10V, $R_{G}$ =1.8 $\Omega$	-	29	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	50	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	25	-	nS
Total Gate Charge	Qg	V 00VI 470A	-	141	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,I <sub>D</sub> =170A,	-	40		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	26.7		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =170A	-		1.2	V
Diode Forward Current	Is		-	-	340	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =I <sub>S</sub>	-	80	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	175	-	nC

#### Notes:

<sup>1.</sup> Repetitive Rating: Pulse width limited by maximum junction temperature.

<sup>2.</sup> These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.

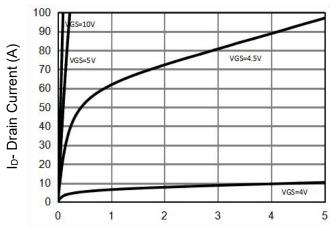
<sup>3.</sup> Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.

<sup>4.</sup> Guaranteed by design, not subject to production

<sup>5.</sup> EAS condition : Tj=25  $^{\circ}\mathrm{C}$  ,V\_DD=40V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 

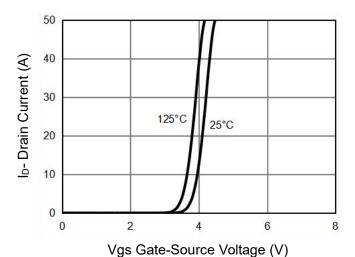


# **Typical Electrical and Thermal Characteristics**



Vds Drain-Source Voltage (V)

**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

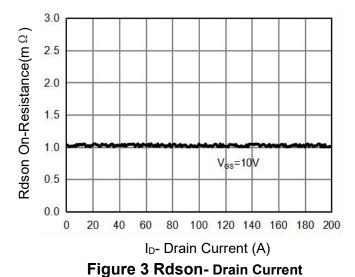


Figure 4 Rdson-Junction Temperature

T<sub>J</sub>-Junction Temperature(°C)

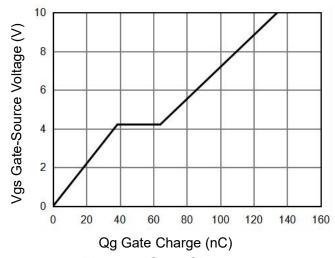


Figure 5 Gate Charge

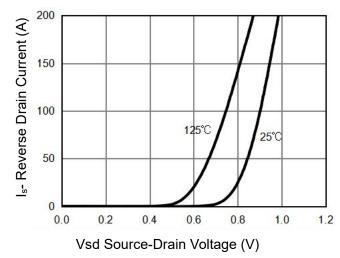


Figure 6 Source- Drain Diode Forward



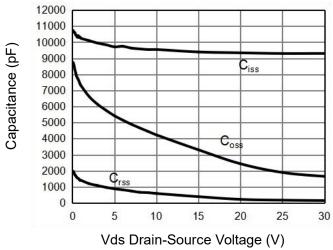


Figure 7 Capacitance vs Vds

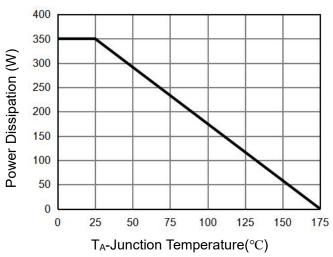


Figure 9 Power De-rating

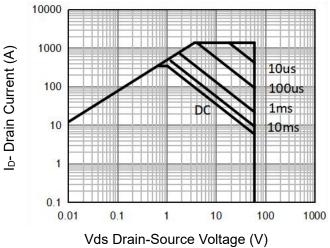


Figure 8 Safe Operation Area(Note2)

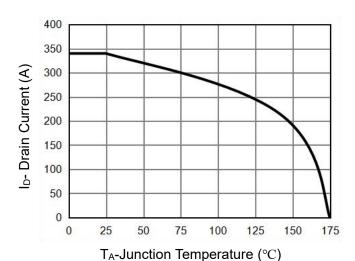
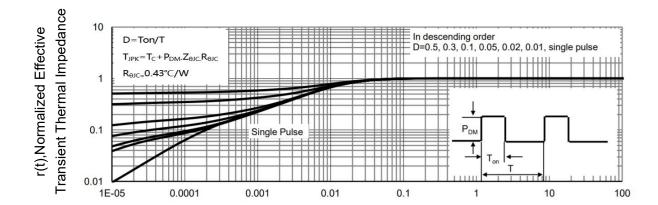


Figure 10 Current De-rating



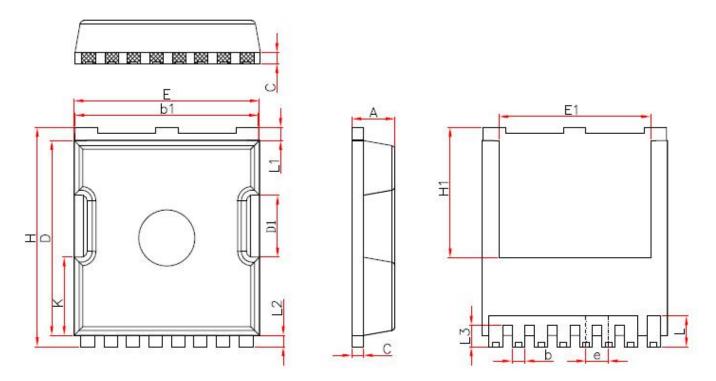
Square Wave Pluse Duration(sec)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 



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# **TOLL Package Information**



Symbol	Millimeters			
VEEC	Min.	Nom.	Max.	
A	2.20	2.30	2.40	
b	0.65	0.75	0.85	
b1	9.70	9.80	9.90	
C	0.50	0.60	0.70	
D	10.30	10.40	10.50	
D1	3.15	3.3	3.45	
Е	9.70	9.90	10.10	
E1	8.00	8.10	8.20	
е	1.10	1.20	1.30	
Н	11.6	11.7	11.8	
H1	6.85	6.95	7.05	
K	4.08	4.18	4. 28	
L	1.60	1.65	2.10	
L1	0.60	0.70	0.80	
L2	0.50	0.60	0.70	
L3	1.05	1.20	1.30	



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